

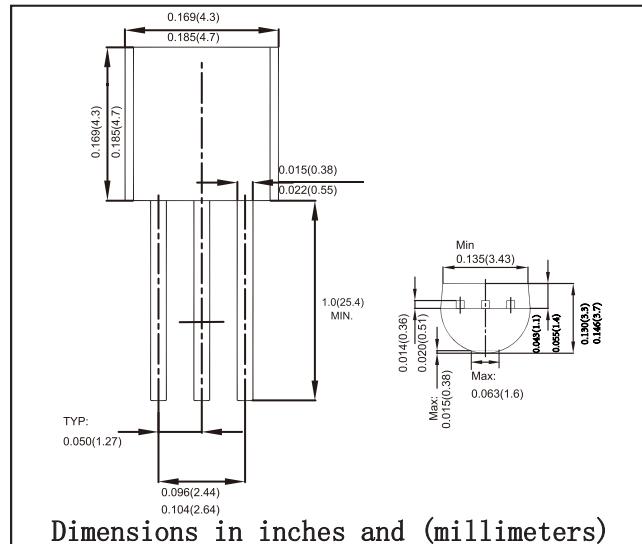
TO-92 Plastic-Encapsulate Transistors

FEATURES

- Low Current
- High Voltage
- TRANSISTOR (NPN)

MECHANICAL DATA

- Case style: TO-92 molded plastic
- Mounting position: any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	200	V
V_{CEO}	Collector-Emitter Voltage	200	V
V_{EBO}	Emitter-Base Voltage	6	V
I_c	Collector Current	0.2	A
P_c	Collector Power Dissipation	625	mW
R_{eJA}	Thermal Resistance From Junction To Ambient	200	°C/W
T_j	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55~+150	°C

ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
MPSA43	TO-92	Bulk	1000pcs/Bag
MPSA43-TA	TO-92	Tape	2000pcs/Box

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.1\text{mA}, I_E=0$	200			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	200			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.1\text{mA}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=160\text{V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=10\text{V}, I_C=1\text{mA}$	25			
	$h_{FE(2)}$	$V_{CE}=10\text{V}, I_C=10\text{mA}$	40		200	
	$h_{FE(3)}$	$V_{CE}=10\text{V}, I_C=30\text{mA}$	50			
Collector-emitter saturation voltage	$V_{CE(sat)(1)}$	$I_C=20\text{mA}, I_B=2\text{mA}$			0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=20\text{mA}, I_B=2\text{mA}$			0.9	V
Transition frequency	f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	50			MHz
Collector output capacitance	C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1\text{MHz}$			4	pF

*Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2.0\%$.

RATINGS AND CHARACTERISTIC CURVES

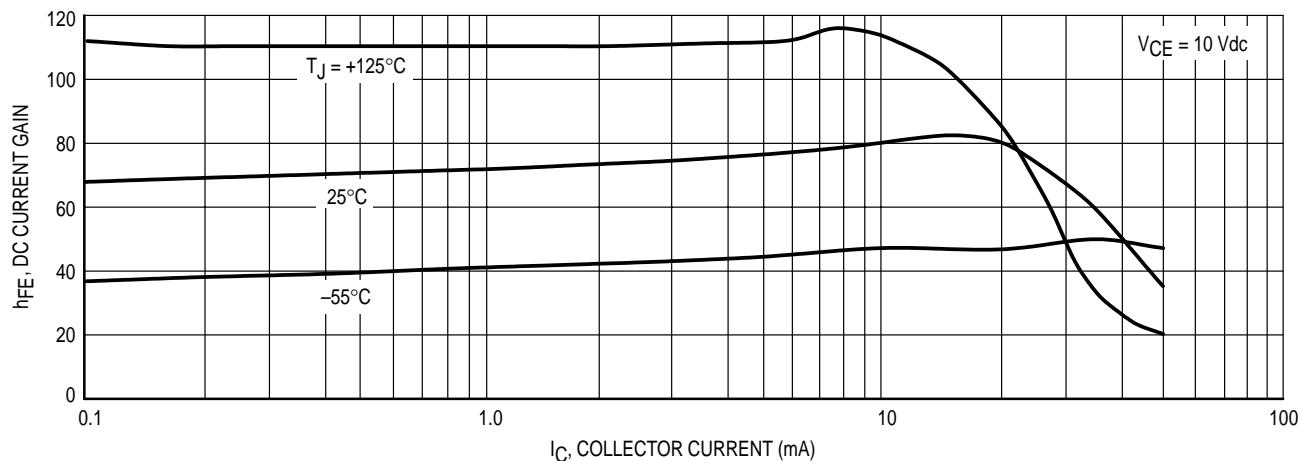


Figure 1. DC Current Gain

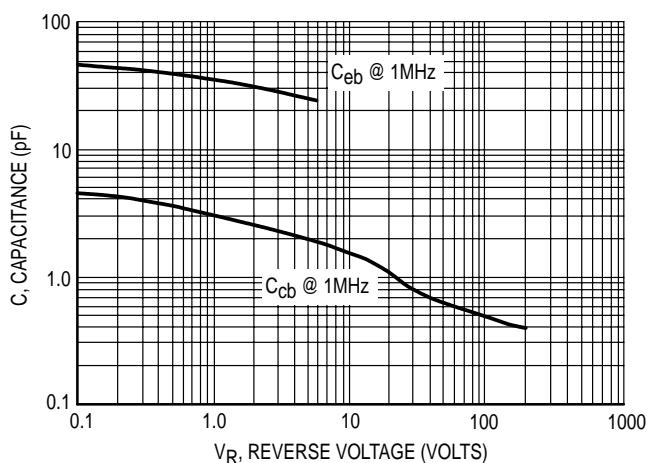


Figure 2. Capacitance

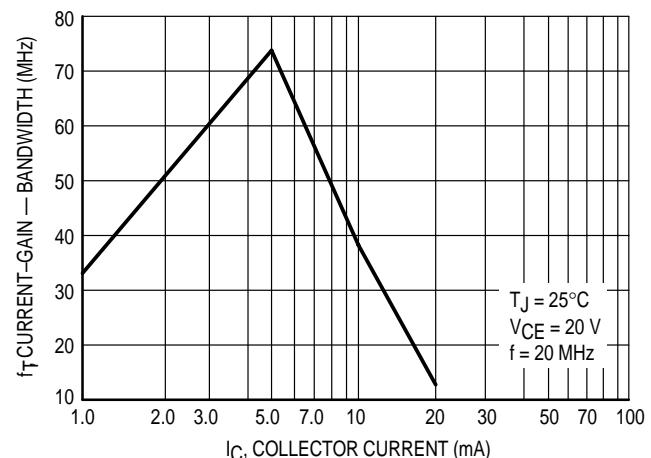


Figure 3. Current-Gain – Bandwidth

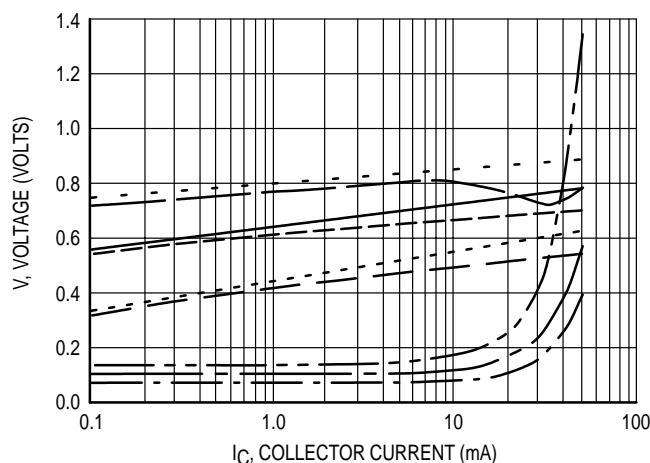


Figure 4. "ON" Voltages

—	$V_{CE(\text{sat})} @ 25^\circ\text{C}, I_C/I_B = 10$
—	$V_{BE(\text{sat})} @ 25^\circ\text{C}, I_C/I_B = 10$
—	$V_{BE(\text{on})} @ 25^\circ\text{C}, V_{CE} = 10\text{ V}$
—	$V_{BE(\text{on})} @ 125^\circ\text{C}, V_{CE} = 10\text{ V}$
—	$V_{BE(\text{on})} @ -55^\circ\text{C}, V_{CE} = 10\text{ V}$